

# 1A, 200V-1000V High Efficient Surface Mount Rectifiers

#### **FEATURES**

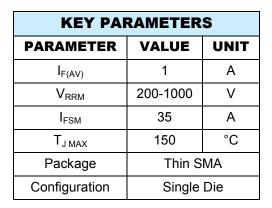
- Glass passivated junction chip
- Ideal for automated placement
- Low power loss, high efficiency
- · Fast switching for high efficiency
- Low profile package
- RoHS Compliant
- Halogen-free according to IEC 61249-2-21

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- Freewheeling application
- Switching mode converters and inverters, computer and telecommunication.

<b>MECHANICAL</b>	<b>DATA</b>
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- Case: Thin SMA
- Molding compound meets UL 94V-0 flammability rating
- Moisture sensitivity level: level 1, per J-STD-020
- Terminal: Pure tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 2 whisker test
- Polarity: As marked
- Weight: 0.029 g (approximately)











Thin SMA

ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25°C unless otherwise noted)							
PARAMETER	SYMBOL	HS1DAL	HS1GAL	HS1JAL	HS1KAL	HS1MAL	UNIT
Marking code on the device		HS1DAL	HS1GAL	HS1JAL	HS1KAL	HS1MAL	
Repetitive peak reverse voltage	$V_{RRM}$	200	400	600	800	1000	٧
Reverse voltage, total rms value	V <sub>R(RMS)</sub>	140	280	420	560	700	V
Forward current	I <sub>F(AV)</sub>	1					Α
Surge peak forward current, single half sine-wave 8.3ms at T <sub>A</sub> = 25°C	I <sub>ESM</sub>			35			А
superimposed on rated load per diode $1.0 \text{ms}$ at $T_A = 25^{\circ}\text{C}$				90			Α
Junction temperature	TJ	-55 to +150				°C	
Storage temperature	T <sub>STG</sub>	-55 to +150					°C

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THERMAL PERFORMANCE					
PARAMETER	SYMBOL	TYP	UNIT		
Junction-to-lead thermal resistance	R <sub>OJL</sub>	29	°C/W		
Junction-to-ambient thermal resistance	R <sub>OJA</sub>	51	°C/W		
Junction-to-case thermal resistance	R <sub>eJC</sub>	22	°C/W		

Thermal Performance Note: Units mounted on PCB (5mm x 5mm Cu pad test board)

PARAMETER		CONDITIONS	SYMBOL	TYP	MAX	UNIT
				0.80	-	V
	HS1DAL	I <sub>F</sub> = 1A, T <sub>J</sub> = 25°C		0.85	1.00	V
		I <sub>F</sub> = 0.5A, T <sub>J</sub> = 125°C		0.65	-	V
		I <sub>F</sub> = 1A, T <sub>J</sub> = 125°C		0.71	0.80	V
		I <sub>F</sub> = 0.5A, T <sub>J</sub> = 25°C		0.84	-	V
	LICACAL	I <sub>F</sub> = 1A, T <sub>J</sub> = 25°C		0.91	1.30	V
	HS1GAL	I <sub>F</sub> = 0.5A, T <sub>J</sub> = 125°C		0.68	-	V
		I <sub>F</sub> = 1A, T <sub>J</sub> = 125°C		0.76	0.86	V
Forward voltage per diode <sup>(1)</sup>	HS1JAL	I <sub>F</sub> = 0.5A, T <sub>J</sub> = 25°C	V <sub>F</sub>	0.92	-	V
		I <sub>F</sub> = 1A, T <sub>J</sub> = 25°C		1.02	1.70	V
		I <sub>F</sub> = 0.5A, T <sub>J</sub> = 125°C		0.73	-	V
		I <sub>F</sub> = 1A, T <sub>J</sub> = 125°C		0.83	1.02	V
	HS1KAL HS1MAL	I <sub>F</sub> = 0.5A, T <sub>J</sub> = 25°C		1.32	-	V
		I <sub>F</sub> = 1A, T <sub>J</sub> = 25°C		1.49	1.70	V
		I <sub>F</sub> = 0.5A, T <sub>J</sub> = 125°C		0.98	-	V
		I <sub>F</sub> = 1A, T <sub>J</sub> = 125°C		1.16	1.39	V
Reverse current @ rated V <sub>R</sub> per diode <sup>(2)</sup>		T <sub>J</sub> = 25°C		-	1	μA
		T <sub>J</sub> = 125°C	l <sub>R</sub>	-	35	μA
	HS1DAL HS1GAL	1 0 5 1 1 0 1	t <sub>rr</sub>	-	50	ns
Reverse recovery time	HS1JAL HS1KAL HS1MAL	I <sub>F</sub> =0.5A,I <sub>R</sub> =1.0A, Irr=0.25A		-	75	ns
	HS1DAL		CJ	20	-	pF
	HS1GAL			17	-	pF
Junction capacitance per diode	HS1JAL	1 MHz, V <sub>R</sub> =4.0V		13	-	pF
	HS1KAL HS1MAL			8	-	pF

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#### Notes:

- (1) Pulse test with PW=0.3 ms
- (2) Pulse test with PW=30 ms



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ORDERING INFORMATION					
ORDERING CODE <sup>(1)</sup>	PACKAGE	PACKING			
HS1xAL M3G	Thin SMA	3,500 / 7" reel			
HS1xAL M2G	Thin SMA	14,000 / 13" reel			

#### Notes:

(1) "x" defines voltage from 200V(HS1DAL) to 1000V(HS1MAL)



#### **CHARACTERISTICS CURVES**

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$ 

Fig.1 Forward Current Derating Curve

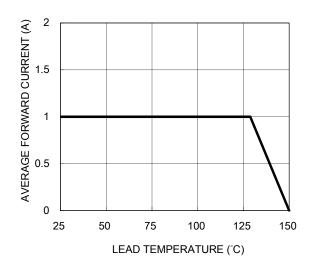


Fig.3 Typical Reverse Characteristics

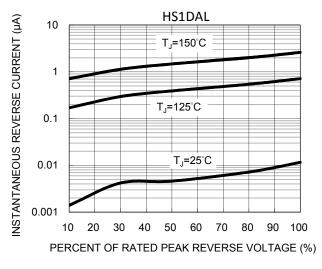


Fig.5 Typical Reverse Characteristics

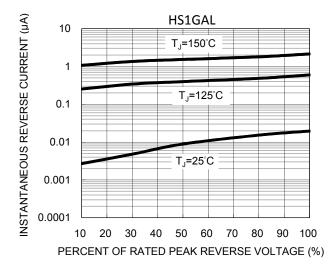


Fig.2 Typical Junction Capacitance

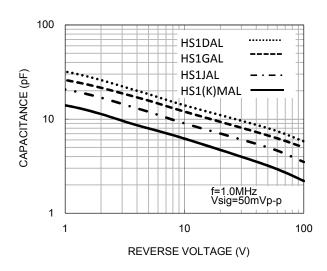
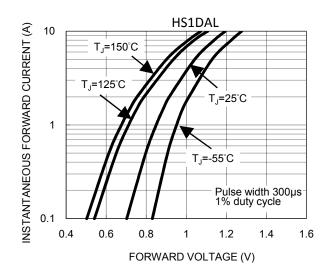


Fig.4 Typical Forward Characteristics



**Fig.6 Typical Forward Characteristics** 

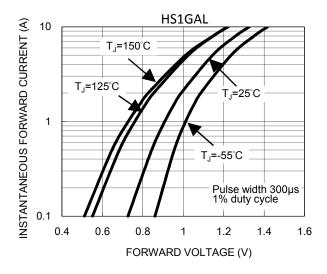




Fig.7 Typical Reverse Characteristics

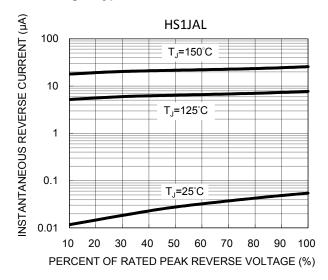


Fig.9 Typical Reverse Characteristics

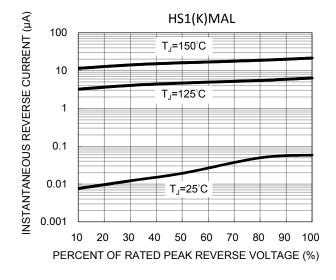


Fig.8 Typical Forward Characteristics

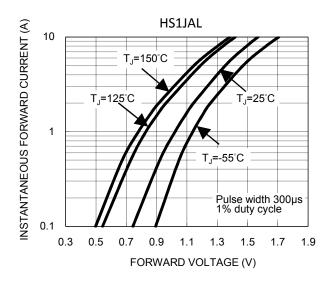


Fig.10 Typical Forward Characteristics

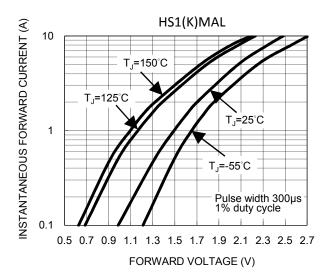
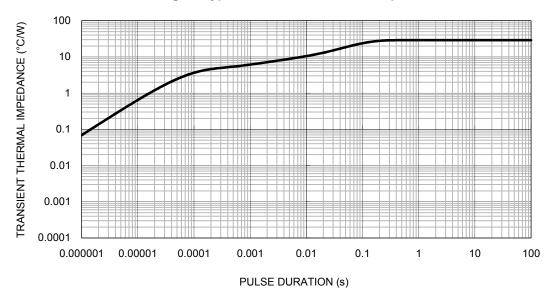


Fig.11 Typical Transient Thermal Impedance

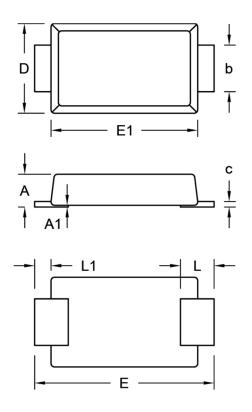


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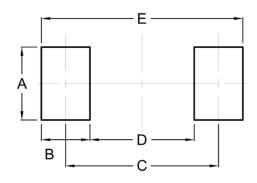
#### **PACKAGE OUTLINE DIMENSIONS**

Thin SMA



DIM.	Unit	(mm)	Unit (inch)	
DIIVI.	Min.	Max.	Min.	Max.
Α	0.90	1.00	0.035	0.039
A1	0.00	0.10	0.000	0.004
b	1.25	1.45	0.049	0.057
С	0.10	0.22	0.004	0.009
D	2.50	2.70	0.098	0.106
E	5.05	5.35	0.199	0.211
E1	4.15	4.35	0.163	0.171
L	0.75	1.20	0.030	0.047
L1	0.30	0.60	0.012	0.024

# **SUGGESTED PAD LAYOUT**



Symbol	Unit (mm)	Unit (inch)	
Α	2.10	0.083	
В	1.40	0.055	
С	4.40	0.173	
D	3.00	0.118	
E	5.80	0.228	

### **MARKING DIAGRAM**



= Marking Code P/N ΥW = Date Code F = Factory Code

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